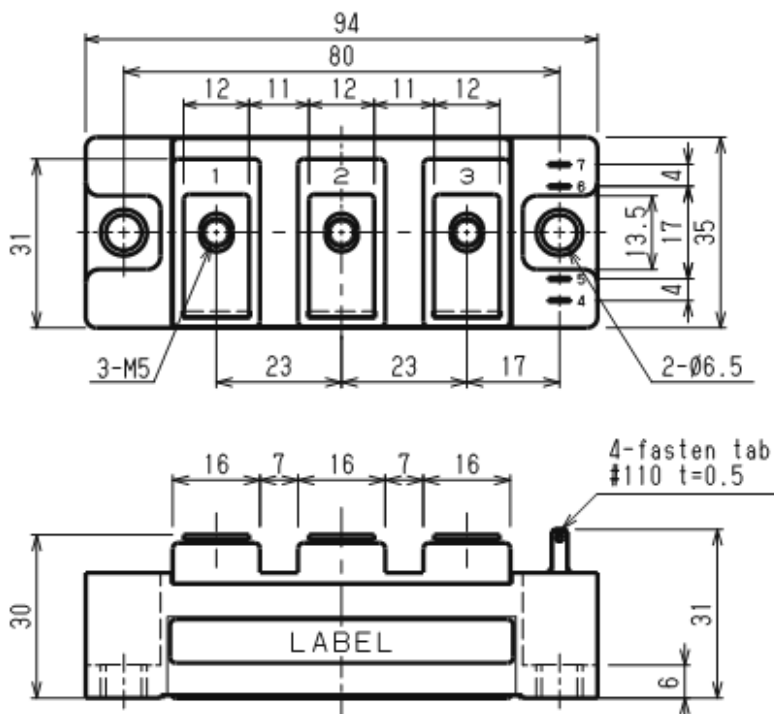
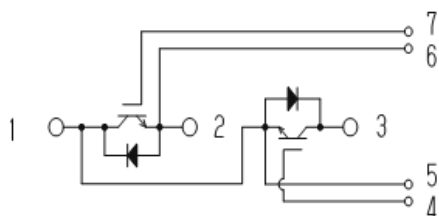


□ 回路図 : *CIRCUIT*

□ 概略図 : *SCHEMATIC DIAGRAM*

Dimension: [mm]



□ 最大定格 : *MAXIMUM RATINGS* (at Tc=25°C unless otherwise specified)

Item		Symbol	Condition	Rated Value	Unit
IGBT	コレクタ・エミッタ間電圧 Collector-Emmitter Voltage	V _{CES}	G-E Short	650	V
	ゲート・エミッタ間電圧 Gate-Emmitter Voltage	V _{GES}	C-E Short	±20	V
	コレクタ電流 Collector Current	I _C	DC T _c =85℃	50	A
		I _{CP}	Pulse ≤ 1ms	100	
	コレクタ損失 Collector Power Dissipation	P _C	T _J =175℃	217	W
T _J =150℃			181		
FWD	繰り返しピーク逆電圧 Repetitive peak reverse voltage	V _{RRM}		650	V
	順電流 Forward Current	I _F		50	A
		I _{FM}	Pulse ≤ 1ms	100	
最大接合温度 Maximum Junction Temperature		T _{JMAX}	瞬時動作(過負荷) Instantaneous Overload	175	℃
接合温度範囲 Junction Temperature Range		T _J		-40~+150	℃
保存温度範囲 Storage Temperature Range		T _{stg}		-40~+125	℃
絶縁耐圧 Isolation Voltage		V _{ISO}	Terminal to Base AC, 1minute	2,500	V (RMS)
締め付けトルク Mounting Torque	Module Base to Heatsink	F _{tor}	M6	3	N・m
	Busbar to Main Terminal		M5	2	

□ 電 気 的 特 性 : **ELECTRICAL CHARACTERISTICS** (at $T_J=25^\circ\text{C}$ unless otherwise specified)

Characteristic			Symbol	Test Condition	Min.	Typ.	Max.	Unit	
IGBT	コレクタ遮断電流 Collector-Emitter Cut-Off Current		ICES	VCE= 650V,VGE= 0V		—	—	1.0	mA
	ゲート漏れ電流 Gate-Emitter Leakage Current		IGES	VGE= ±20V,VCE= 0V		—	—	1.0	μA
	コレクタ・エミッタ間飽和電圧 Collector-Emitter Saturation Voltage		VCE(sat.)	IC= 50A,VGE= 15V (chip level)	TJ=25℃	—	1.45	1.95	V
					TJ=125℃	—	1.65	—	
					TJ=150℃	—	1.70	—	
	ゲートしきい値電圧 Gate-Emitter Threshold Voltage		VGE(th.)	VCE= 10V,IC= 1mA		4.8	—	7.0	V
	入力容量 Input Capacitance		Cies	VCE= 25V,VGE= 0V,f= 1MHz		—	4.5	—	nF
	出力容量 Output Capacitance		Coes			—	0.2	—	
	帰還容量 Reverse Transfer Capacitance		Cres			—	0.15	—	
	ゲート電荷量 Gate Charge			Qg	Vcc=300V, Ic=50A, VGE=-15~+15V		—	425	—
スイッチング時間 Switching Time	上昇時間 Rise Time	tr	VCC= 300V Ls=38nH IC= 50A Inductive Load RG= 20Ω VGE= ±15V Tj= 150℃		—	78	—	ns	
	ターンオン遅延時間 Turn-on Delay Time	td(on)			—	134	—		
	下降時間 Fall Time	tf			—	72	—		
	ターンオフ遅延時間 Turn-off Delay Time	td(off)			—	347	—		
FWD	順電圧 Peak Forward Voltage		VF	IF= 50A,VGE=0V (chip level)	TJ=25℃	—	1.70	2.20	V
					TJ=125℃	—	1.60	—	
					TJ=150℃	—	1.55	—	
逆回復時間 Reverse Recovery Time		trr	VCC= 300V Ls=38nH IC= 50A Inductive Load RG= 20Ω VGE= ±15V Tj= 150℃		—	140	—	ns	
内部配線抵抗 Internal Lead Resistance			RCC+EE'	主端子—チップ間 / 1素子 Main Terminal - Chip / Per 1 Arm		—	—	1	mΩ
内部インダクタンス Stray Inductance			LSCE	メイン端子3—2間 Main Terminal 3 - Main Terminal 2		—	30	—	nH

□ 熱 的 特 性 : **THERMAL CHARACTERISTICS**

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
熱抵抗 Thermal Resistance	I G B T	Rth(j-c)	Junction to Case Per 1 Arm (Tc測定点:チップ直下)	—	—	0.69	°C/W
	F W D			—	—	1.66	
接触熱抵抗 Thermal Resistance	I G B T	Rth(c-f)	Case to heatsink Per 1 Arm Paste=1W/(m ² °C)	—	0.10	—	
	F W D			—	0.17	—	

□ 特性图 : CHARACTERISTICS CURVES

Fig.1- Output Characteristics (Typical)

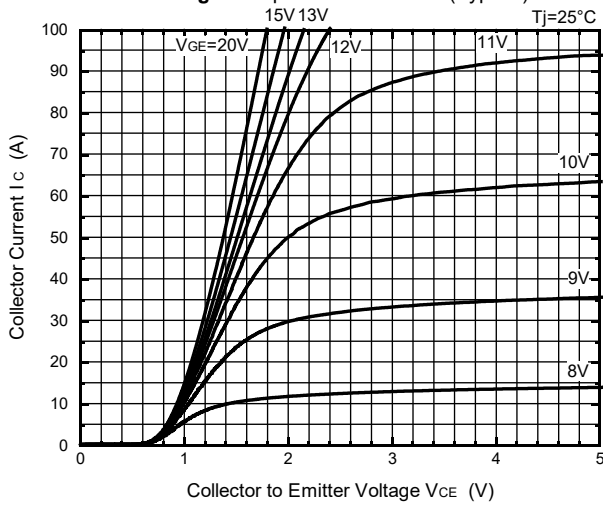


Fig.2- Saturation Voltage Characteristics (Typical)

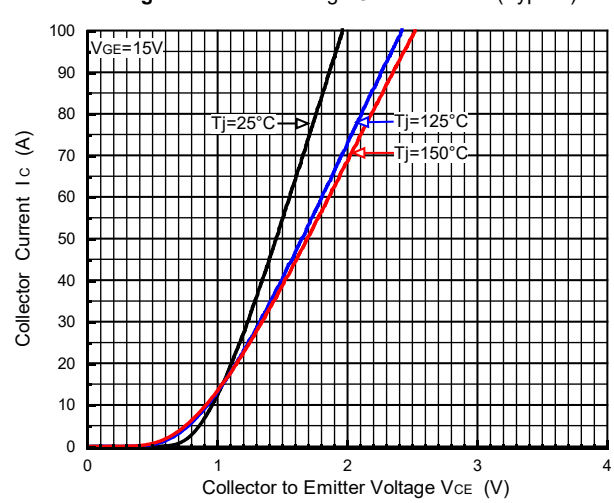


Fig.3- Transfer Characteristics (Typical)

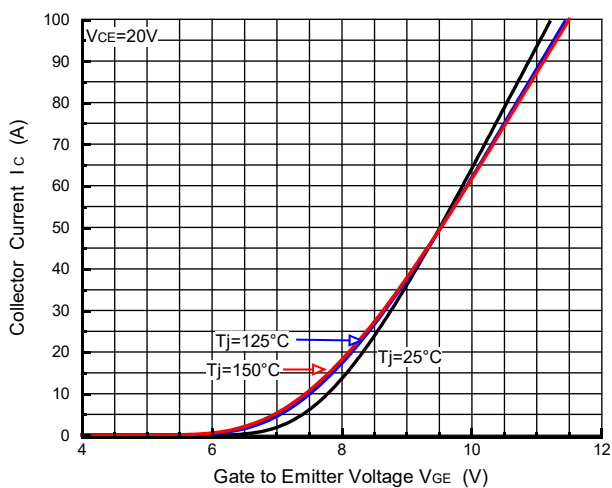


Fig.4- Gate Charge vs. Collector to Emitter Voltage (Typical)

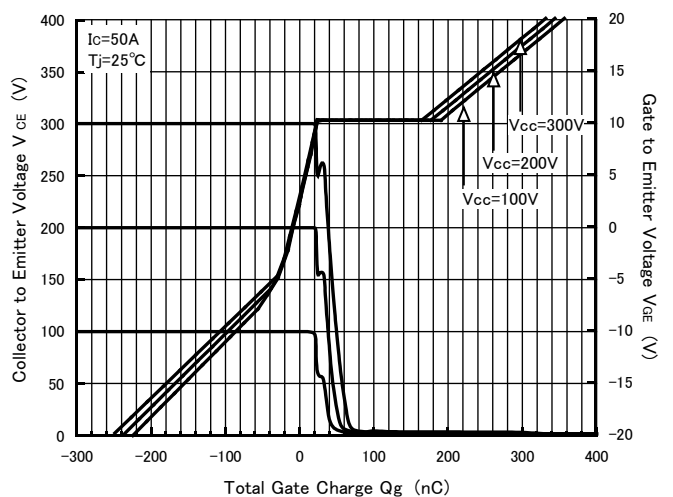


Fig.5- Collector Current vs. Switching Time (Typical)

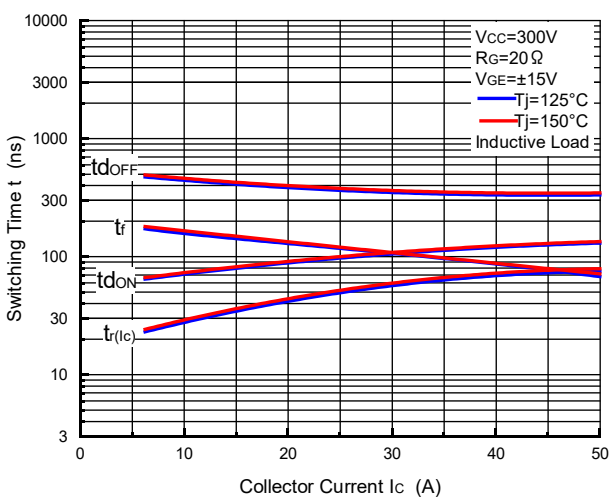
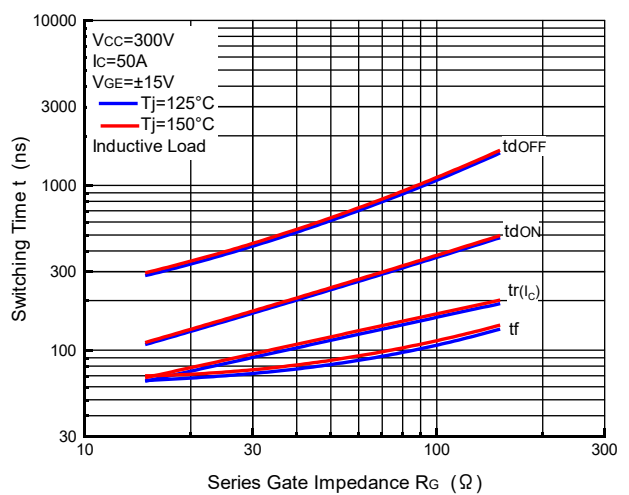


Fig.6- Series Gate Impedance vs. Switching Time (Typical)



特性図 : CHARACTERISTICS CURVES

Fig.7- Collector Current vs. Switching Loss (Typical)

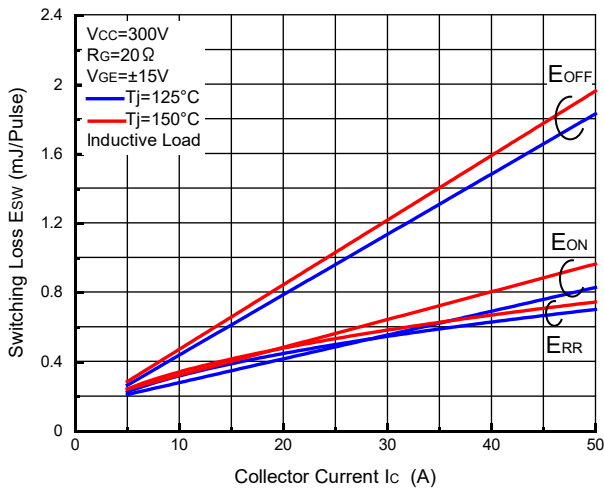


Fig.8- Series Gate Impedance vs. Switching Loss (Typical)

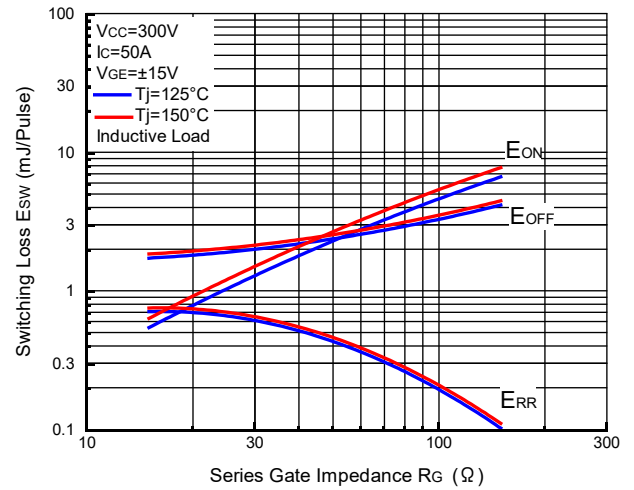


Fig.9- Forward Characteristics of Free Wheeling Diode (Typical)

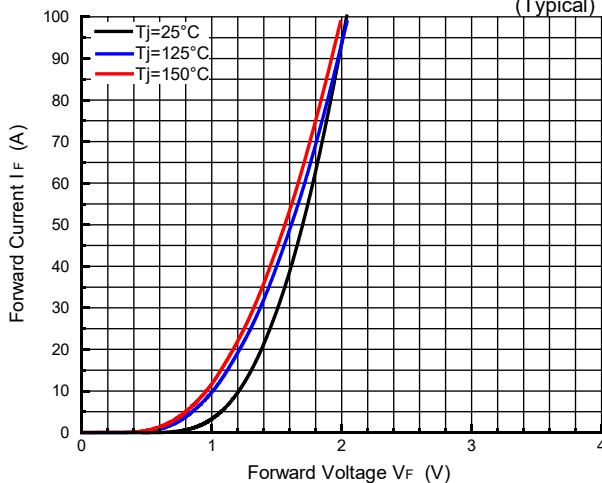


Fig.10- FWD Reverse Recovery Characteristics (Typical)

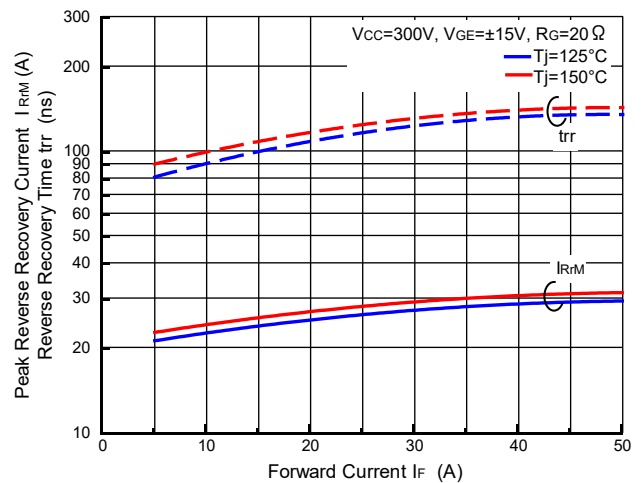


Fig.11- Reverse Bias Safe Operating Area

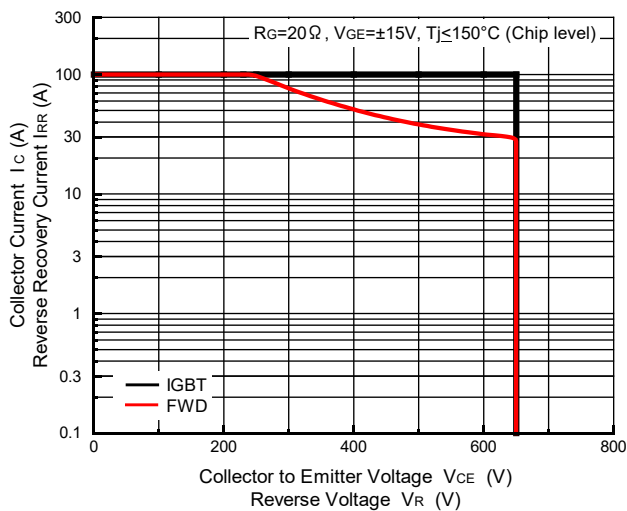
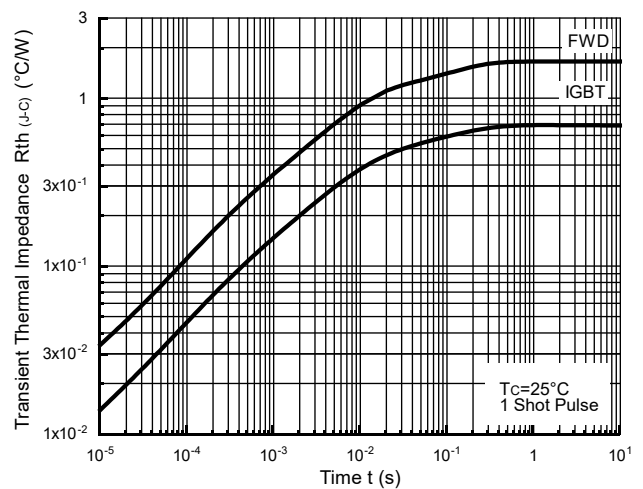


Fig.12- Transient Thermal Impedance



1. ご採用に際しては、別途仕様書をご請求の上、ご確認をお願いいたします。
If you wish to use any such product, please be sure to refer to the specifications issued by Shindengen.
2. 本資料に記載されている当社製品の品質水準は、一般的な信頼度が要求される標準用途を意図しています。その製品の故障や誤動作が直接生命や人体に影響を及ぼすような極めて高い品質、信頼度を要求される特別、特定用途の機器、装置にご使用の場合には必ず事前に当社へご連絡の上、確認を得て下さい。当社の製品の品質水準は以下のように分類しております。
All products described or contained herein are designed with a quality level intended for use in standard applications requiring an ordinary level of reliability. If these products are to be used in equipment or devices for special or specific applications requiring an extremely high grade of quality or reliability in which failures or malfunctions of products may directly affect human life or health, a local Shindengen office must be contacted in advance to confirm that the intended use of the product is appropriate. Shindengen products are grouped into the following three applications according to the quality grade.
【標準用途】
コンピュータ、OA 等の事務機器、通信用端末機器、計測器、AV 機器、アミューズメント機器、家電、工作機器、パーソナル機器、産業用機器等
【Standard applications】
Computers, office automation and other office equipment, communication terminals, test and measurement equipment, audio/visual equipment, amusement equipment, consumer electronics, machine tools, personal electronic equipment, industrial equipment, etc.
【特別用途】
輸送機器(車載、船舶等)、基幹用通信機器、交通信号機器、防災/防犯機器、各種安全機器、医療機器等
【Special applications】
Transportation equipment (vehicles, ships, etc.), trunk-line communication equipment, traffic signal control systems, anti-disaster/crime systems, safety equipment, medical equipment, etc.
【特定用途】
原子力制御システム、航空機器、航空宇宙機器、海中継機器、生命維持のための装置、システム等
【Specific applications】
Nuclear reactor control systems, aircraft, aerospace equipment, submarine repeaters, life support equipment and systems, etc.
3. 当社は品質と信頼性の向上に絶えず努めていますが、必要に応じ、安全性を考慮した冗長設計、延焼防止設計、誤動作防止設計等の手段により結果として人身事故、火災事故、社会的な損害等が防止できるようご検討下さい。
Although Shindengen continuously endeavors to enhance the quality and reliability of its products, customers are advised to consider and take safety measures in their design, such as redundancy, fire containment and anti-failure, so that personal injury, fires, or societal damages can be prevented.
4. 本資料に記載されている内容は、製品改良などのためお断りなしに変更することがありますのでご了承下さい。製品のご購入に際しましては事前に当社または特約店へ最新の情報をご確認下さい。
Please note that all information described or contained herein is subject to change without notice due to product upgrades and other reasons. When buying Shindengen products, please contact the Company's offices or distributors to obtain the latest information.
5. 本資料の使用によって起因する損害または特許権その他権利の侵害に関しては、当社は一切その責任を負いません。
Shindengen shall not bear any responsibility with regards to damages or infringement of any third-party patent rights and other intellectual property rights incurred due to the use of information on this website.
6. 本資料によって第三者または当社の特許権その他権利の実施に対する保証または実施権の許諾を行うものではありません。
The information and materials on this website neither warrant the use of Shindengen's or any third party's patent rights and other intellectual property rights, nor grant license to such rights.
7. 本資料に記載されている製品が、外国為替及び外国貿易管理法に基づき規制されている場合、輸出には同法に基づく日本国政府の輸出許可が必要です。
In the event that any product described or contained herein falls under the category of strategic products controlled under the Foreign Exchange and Foreign Trade Control Law of Japan, exporting of such products shall require an export license from the Japanese government in accordance with the above law.
8. 本資料の一部または全部を当社に無断で転載または複製することを堅くお断りいたします。
No reprinting or reproduction of the materials on this website, either in whole or in part, is permitted without proper authorization from Shindengen.